/ IC

■

LN8240 / IC

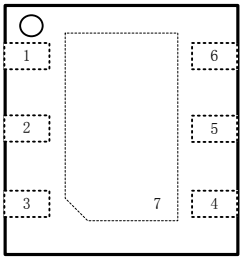
LN8240 MOSFET IC

LN8240

■

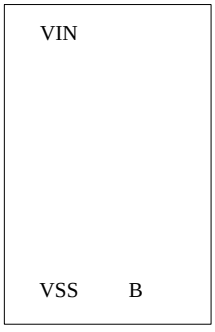
- MOSFET 20m
-
  30mV
  30mV
-
-
-
  2.2uA
  0.1uA
-
-

■



DFN2x2-6L
(TOP VIEW)

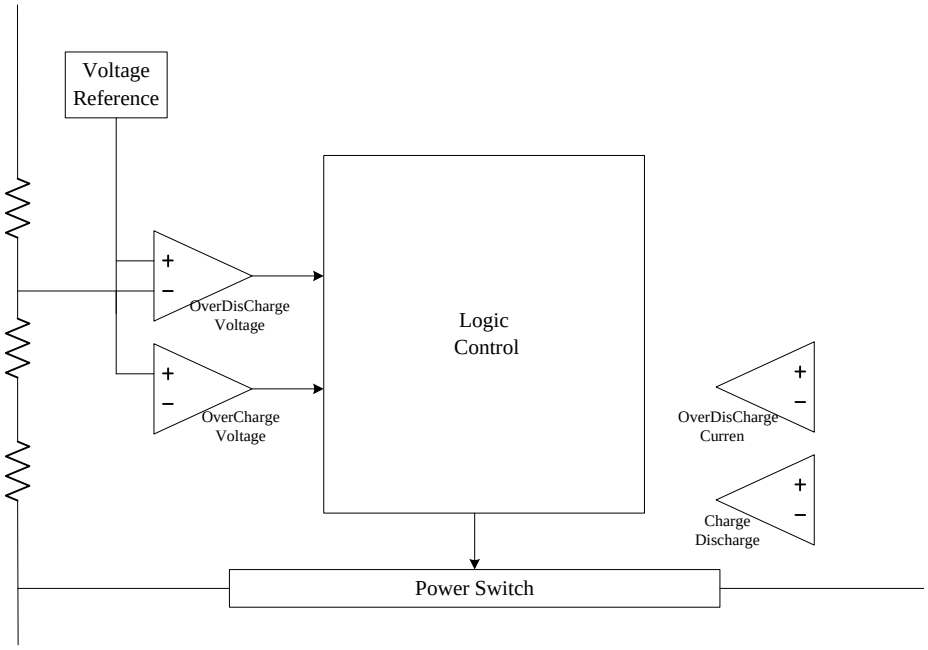
■



■

LN8240 4

DFN2*2-6L		
VIN	1	
GND	2	/ GND
GND	3	
BATN	4	
BATN	5	
BATN	6	
	7	GND BATN



Parameter	Symbol	Max	Unit
	VIN	VSS-0.3 VSS+6.0	V
MOS	BARTN	VSS-6.0 VSS+10	
	PD@TA=25	0.4	W

■

■

（V_{EN}= V_{DD} =3.6V, Gain=24dB, R_L=8 ,T_A=25 ,unless otherwise specification）

	Test Condition	Min	Typ	Max	Unit

V_{CU} t_{CU}

BATN

V_{CUR}

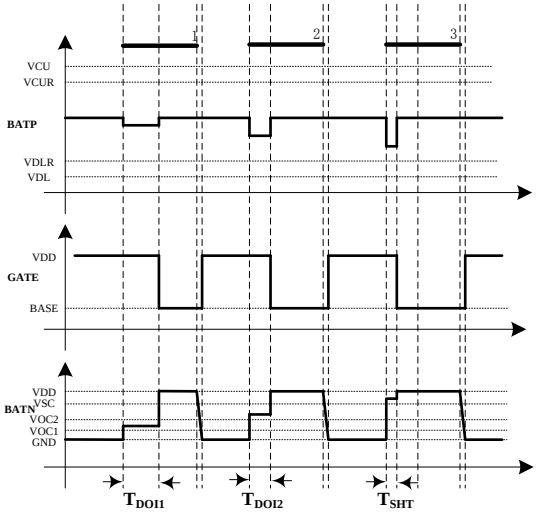
V_{DL}

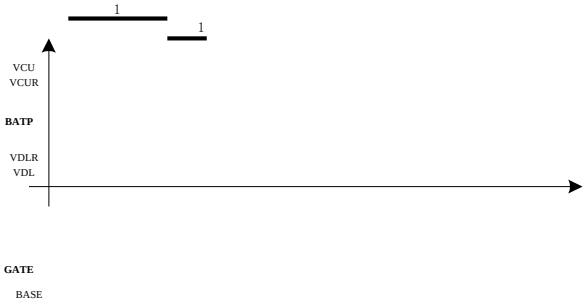
t_{DL} BATN I_{SD}

MOS

I_{OC1} I_{SC} T_{OC1}

T_{SC}





■

- **DFN2x2-6L**